

ADG608/ADG609—SPECIFICATIONS

DUAL SUPPLY¹ ($V_{DD} = +5 \text{ V} \pm 10\%$, $V_{SS} = -5 \text{ V} \pm 10\%$, GND = 0 V, unless otherwise noted)

Parameter	B Version +25°C -40°C to +85°C		T Version +25°C -55°C to +125°C		Units	Test Conditions/ Comments
ANALOG SWITCH						
Analog Signal Range	V_{SS} to V_{DD}		V_{SS} to V_{DD}		V	
R_{ON}	22		22		Ω typ	$-3.5 \text{ V} \leq V_S \leq +3.5 \text{ V}$, $I_S = -1 \text{ mA}$; $V_{DD} = +4.5 \text{ V}$, $V_{SS} = -4.5 \text{ V}$;
ΔR_{ON}	30	35	30	40	Ω max	Test Circuit 1
R_{ON} Match	5	6	5	6	Ω max	$-3 \text{ V} \leq V_S \leq +3 \text{ V}$, $I_{DS} = -1 \text{ mA}$; $V_{DD} = +5 \text{ V}$, $V_{SS} = -5 \text{ V}$
$V_S = 0 \text{ V}$, $I_{DS} = -1 \text{ mA}$; $V_{DD} = +5 \text{ V}$, $V_{SS} = -5 \text{ V}$						
LEAKAGE CURRENTS						
Source OFF Leakage I_S (OFF)	± 0.05		± 0.05		nA typ	$V_{DD} = +5.5 \text{ V}$, $V_{SS} = -5.5 \text{ V}$
Drain OFF Leakage I_D (OFF)	± 0.5	± 2	± 0.5	± 10	nA max	$V_D = \pm 4.5 \text{ V}$, $V_S = \mp 4.5 \text{ V}$;
ADG608	± 0.05		± 0.05		nA typ	Test Circuit 2
ADG609	± 0.5	± 2	± 0.5	± 10	nA max	$V_D = \pm 4.5 \text{ V}$, $V_S = \mp 4.5 \text{ V}$;
Channel ON Leakage I_D , I_S (ON)	± 0.05		± 0.05		nA typ	Test Circuit 3
ADG608	± 0.5	± 3	± 0.5	± 20	nA max	$V_S = V_D = \pm 4.5 \text{ V}$;
ADG609	± 0.5	± 1.5	± 0.5	± 10	nA max	Test Circuit 4
DIGITAL INPUTS						
Input High Voltage, V_{INH}	2.4		2.4		V min	
Input Low Voltage, V_{INL}	0.8		0.8		V max	
Input Current						
I_{INL} or I_{INH}	± 1		± 1		μA max	
C_{IN} , Digital Input Capacitance	5		5		pF typ	$V_{IN} = 0$ or V_{DD}
DYNAMIC CHARACTERISTICS ²						
$t_{TRANSITION}$	50		50		ns typ	$R_L = 300 \Omega$, $C_L = 35 \text{ pF}$;
	75	90	75	100	ns max	$V_{S1} = \pm 3.5 \text{ V}$, $V_{S8} = \mp 3.5 \text{ V}$;
					Test Circuit 5	
t_{OPEN}	10		10		ns min	$R_L = 300 \Omega$, $C_L = 35 \text{ pF}$;
					$V_S = +3.5 \text{ V}$; Test Circuit 6	
t_{ON} (EN)	50		50		ns typ	$R_L = 300 \Omega$, $C_L = 35 \text{ pF}$;
	75	90	75	100	ns max	$V_S = +3.5 \text{ V}$; Test Circuit 7
t_{OFF} (EN)	30		30		ns typ	$R_L = 300 \Omega$, $C_L = 35 \text{ pF}$;
	45	60	45	75	ns max	$V_S = +3.5 \text{ V}$; Test Circuit 7
Charge Injection	6		6		pC typ	$V_S = 0 \text{ V}$, $R_S = 0 \Omega$, $C_L = 1 \text{ nF}$;
OFF Isolation	85		85		dB typ	Test Circuit 8
Channel-to-Channel Crosstalk	85		85		dB typ	$R_L = 1 \text{ k}\Omega$, $C_L = 15 \text{ pF}$, $f = 100 \text{ kHz}$;
					$V_S = 3 \text{ V rms}$; Test Circuit 9	
C_S (OFF)	9		9		pF typ	$R_L = 1 \text{ k}\Omega$, $C_L = 15 \text{ pF}$, $f = 100 \text{ kHz}$;
C_D (OFF)					Test Circuit 10	
ADG608	40		40		pF typ	
ADG609	20		20		pF typ	
C_D (ON)						
ADG608	54		54		pF typ	
ADG609	34		34		pF typ	
POWER REQUIREMENTS						
I_{DD}	0.05	0.2	0.05	0.2	μA typ	$V_{IN} = 0 \text{ V}$ or V_{DD}
	0.2	2	0.2	2	μA max	
I_{SS}	0.01	0.1	0.01	0.1	μA typ	
	0.1	1	0.1	1	μA max	

NOTES

¹Temperature ranges are as follows: B Version: -40°C to +85°C; T Version: -55°C to +125°C.

²Guaranteed by design, not subject to production test.

Specifications subject to change without notice.

SINGLE SUPPLY¹ ($V_{DD} = +5 \text{ V} \pm 10\%$, $V_{SS} = 0 \text{ V}$, GND = 0 V, unless otherwise noted)

Parameter	B Version +25°C to -40°C to +85°C		T Version +25°C to -55°C to +125°C		Units	Test Conditions/ Comments
ANALOG SWITCH						
Analog Signal Range	0 to V_{DD}		0 to V_{DD}		V	
R_{ON}	40		40	Ω typ		$V_S = +3.5 \text{ V}$, $I_S = -1 \text{ mA}$;
	50	60	50	Ω max		$V_{DD} = +4.5 \text{ V}$; Test Circuit 1
ΔR_{ON}	5	6	5	Ω max		$+1 \text{ V} \leq V_S \leq +3 \text{ V}$, $I_{DS} = -1 \text{ mA}$;
R_{ON} Match	2	3	2	Ω max		$V_{DD} = +5 \text{ V}$ $V_S = 0 \text{ V}$, $I_{DS} = -1 \text{ mA}$; $V_{DD} = +5 \text{ V}$
LEAKAGE CURRENTS						
Source OFF Leakage I_S (OFF)	± 0.05		± 0.05	nA typ		$V_{DD} = +5.5 \text{ V}$
	± 0.5	± 2	± 0.5	nA max		$V_D = 4.5 \text{ V}/0.1 \text{ V}$, $V_S = 0.1 \text{ V}/4.5 \text{ V}$;
Drain OFF Leakage I_D (OFF)	± 0.05		± 0.05	nA typ		Test Circuit 2
ADG608	± 0.5	± 2	± 0.5	nA max		$V_D = 4.5 \text{ V}/0.1 \text{ V}$, $V_S = 0.1 \text{ V}/4.5 \text{ V}$;
ADG609	± 0.5	± 1	± 0.5	nA max		Test Circuit 3
Channel ON Leakage I_D , I_S (ON)	± 0.05		± 0.05	nA typ		$V_S = V_D = 4.5 \text{ V}/0.1 \text{ V}$;
ADG608	± 0.5	± 3	± 0.5	nA max		Test Circuit 4
ADG609	± 0.5	± 1.5	± 0.5	nA max		
DIGITAL INPUTS						
Input High Voltage, V_{INH}	2.4		2.4		V min	
Input Low Voltage, V_{INL}	0.8		0.8		V max	
Input Current						
I_{INL} or I_{INH}	± 1		± 1		μA max	
C_{IN} , Digital Input Capacitance	5		5	pF typ		$V_{IN} = 0$ or V_{DD}
DYNAMIC CHARACTERISTICS ²						
$t_{TRANSITION}$	80		80	ns typ		$R_L = 300 \Omega$, $C_L = 35 \text{ pF}$;
	100	130	100	ns max		$V_{SI} = 3.5 \text{ V}/0 \text{ V}$, $V_{SS} = 0 \text{ V}/3.5 \text{ V}$;
						Test Circuit 5
t_{OPEN}	10		10	ns min		$R_L = 300 \Omega$, $C_L = 35 \text{ pF}$;
						$V_S = +3.5 \text{ V}$; Test Circuit 6
t_{ON} (EN)	80		80	ns typ		$R_L = 300 \Omega$, $C_L = 35 \text{ pF}$;
	100	130	100	ns max		$V_S = +3.5 \text{ V}$; Test Circuit 7
t_{OFF} (EN)	40		40	ns typ		$R_L = 300 \Omega$, $C_L = 35 \text{ pF}$;
	50	60	50	ns max		$V_S = +3.5 \text{ V}$; Test Circuit 7
Charge Injection	0.5		0.5	pC typ		$V_S = 0 \text{ V}$, $R_S = 0 \Omega$, $C_L = 1 \text{ nF}$;
	3		3	pC max		Test Circuit 8
OFF Isolation	85		85	dB typ		$R_L = 1 \text{k}\Omega$, $C_L = 15 \text{ pF}$, $f = 100 \text{ kHz}$;
						$V_S = 1.5 \text{ V rms}$; Test Circuit 9
Channel-to-Channel Crosstalk	85		85	dB typ		$R_L = 1 \text{k}\Omega$, $C_L = 15 \text{ pF}$, $f = 100 \text{ kHz}$;
						Test Circuit 10
C_S (OFF)	9		9	pF typ		
C_D (OFF)						
ADG608	40		40	pF typ		
ADG609	20		20	pF typ		
C_D (ON)						
ADG608	54		54	pF typ		
ADG609	34		34	pF typ		
POWER REQUIREMENTS						
I_{DD}	0.05	0.2	0.05	μA typ		$V_{IN} = 0 \text{ V}$ or V_{DD}
	0.2	2	0.2	μA max		

NOTES

¹Temperature ranges are as follows: B Version: -40°C to +85°C; T Version: -55°C to +125°C.²Guaranteed by design, not subject to production test.

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ADG608/ADG609—SPECIFICATIONS

SINGLE SUPPLY¹ ($V_{DD} = +3.3\text{ V} \pm 10\%$, $V_{SS} = 0\text{ V}$, GND = 0 V, unless otherwise noted)

Parameter	B Version +25°C -40°C to +85°C		T Version +25°C -55°C to +125°C		Units	Test Conditions/ Comments
ANALOG SWITCH						
Analog Signal Range	0 to V_{DD}		0 to V_{DD}		V	
R_{ON}	60		60		Ω typ	$V_S = +1.5\text{ V}$, $I_S = -1\text{ mA}$;
	90	100	90	120	Ω max	$V_{DD} = +3\text{ V}$; Test Circuit 1
R_{ON} Match	3	3	3	3	Ω max	$V_S = 0\text{ V}$, $I_{DS} = -1\text{ mA}$, $V_{DD} = +3.3\text{ V}$
LEAKAGE CURRENTS						
Source OFF Leakage I_S (OFF)	± 0.05		± 0.05		nA typ	$V_{DD} = +3.6\text{ V}$
	± 0.5	± 2	± 0.5	± 10	nA max	$V_D = 2.6\text{ V}/0.1\text{ V}$, $V_S = 0.1\text{ V}/2.6\text{ V}$;
Drain OFF Leakage I_D (OFF)	± 0.05		± 0.05		nA typ	Test Circuit 2
ADG608	± 0.5	± 2	± 0.5	± 10	nA max	$V_D = 2.6\text{ V}/0.1\text{ V}$, $V_S = 0.1\text{ V}/2.6\text{ V}$;
ADG609	± 0.5	± 1	± 0.5	± 5	nA max	Test Circuit 3
Channel ON Leakage I_D , I_S (ON)	± 0.05		± 0.05		nA typ	$V_S = V_D = 2.6\text{ V}/0.1\text{ V}$;
ADG608	± 0.5	± 3	± 0.5	± 20	nA max	Test Circuit 4
ADG609	± 0.5	± 1.5	± 0.5	± 10	nA max	
DIGITAL INPUTS						
Input High Voltage, V_{INH}	2.4		2.4		V min	
Input Low Voltage, V_{INL}	0.8		0.8		V max	
Input Current						
I_{INL} or I_{INH}	± 1		± 1		μA max	$V_{IN} = 0$ or V_{DD}
C_{IN} , Digital Input Capacitance	5		5		pF typ	
DYNAMIC CHARACTERISTICS ²						
$t_{TRANSITION}$	120		120		ns typ	$R_L = 300\text{ }\Omega$, $C_L = 35\text{ pF}$;
	170	225	170	250	ns max	$V_{S1} = 1.5\text{ V}/0\text{ V}$, $V_{S8} = 0\text{ V}/1.5\text{ V}$;
t_{OPEN}	10		10		ns min	Test Circuit 5
t_{ON} (EN)	120		120		ns typ	$R_L = 300\text{ }\Omega$, $C_L = 35\text{ pF}$;
	170	225	170	250	ns max	$V_S = +1.5\text{ V}$; Test Circuit 6
t_{OFF} (EN)	40		40		ns typ	$R_L = 300\text{ }\Omega$, $C_L = 35\text{ pF}$;
	60	75	60	90	ns max	$V_S = +1.5\text{ V}$; Test Circuit 7
Charge Injection	0.5		0.5		pC typ	$R_L = 300\text{ }\Omega$, $C_L = 35\text{ pF}$;
	3		3		pC max	$V_S = +1.5\text{ V}$; Test Circuit 7
OFF Isolation	85		85		dB typ	$V_S = 0\text{ V}$, $R_S = 0\text{ }\Omega$, $C_L = 1\text{ nF}$;
Channel-to-Channel Crosstalk	85		85		dB typ	Test Circuit 8
C_S (OFF)	9		9		pF typ	$R_L = 1\text{ k}\Omega$, $C_L = 15\text{ pF}$, $f = 100\text{ kHz}$;
C_D (OFF)						$V_S = 1\text{ V rms}$; Test Circuit 9
ADG608	40		40		pF typ	$R_L = 1\text{ k}\Omega$, $C_L = 15\text{ pF}$, $f = 100\text{ kHz}$;
ADG609	20		20		pF typ	Test Circuit 10
C_D (ON)						
ADG608	54		54		pF typ	
ADG609	34		34		pF typ	
POWER REQUIREMENTS						
I_{DD}	0.05	0.2	0.05	0.2	μA typ	$V_{IN} = 0\text{ V}$ or V_{DD}
	0.2	2	0.2	2	μA max	

NOTES

¹Temperature ranges are as follows: B Version: -40°C to +85°C; T Version: -55°C to +125°C.

²Guaranteed by design, not subject to production test.

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ABSOLUTE MAXIMUM RATINGS¹(T_A = +25°C unless otherwise noted)

V _{DD} to V _{SS}	+13 V
V _{DD} to GND	-0.3 V to +6.5 V
V _{SS} to GND	+0.3 V to -6.5 V
Analog, Digital Inputs ²	-0.3 V to V _{DD} + 2 V or 20 mA, Whichever Occurs First
Continuous Current, S or D	20 mA
Peak Current, S or D (Pulsed at 1 ms, 10% Duty Cycle Max)	40 mA
Operating Temperature Range		
Industrial (B Version)	-40°C to +85°C
Extended (T Version)	-55°C to +125°C
Storage Temperature Range	-65°C to +150°C
Junction Temperature	+150°C
Plastic DIP Package		
θ _{JA} , Thermal Impedance	117°C/W
Lead Temperature, Soldering (10 sec)	+260°C

SOIC Package

θ_{JA}, Thermal Impedance 77°C/W

Lead Temperature, Soldering

Vapor Phase (60 sec) +215°C

Infrared (15 sec) +220°C

TSSOP Package

θ_{JA}, Thermal Impedance 158°C/W

Lead Temperature, Soldering

Vapor Phase (60 sec) +215°C

Infrared (15 sec) +220°C

ESD Rating >5000 V

NOTES

¹Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Only one absolute maximum rating may be applied at any one time.

²Overtvoltages at A, S, D or EN will be clamped by internal diodes. Current should be limited to the maximum ratings given.

Table I. ADG608 Truth Table

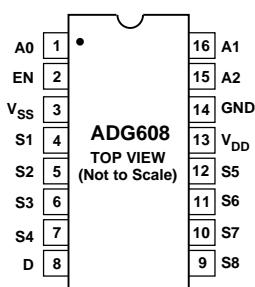
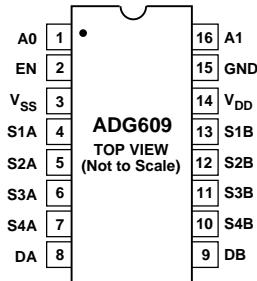
A2	A1	A0	EN	ON SWITCH
X	X	X	0	NONE
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8

X = Don't Care

Table II. ADG609 Truth Table

A1	A0	EN	ON SWITCH PAIR
X	X	0	NONE
0	0	1	1
0	1	1	2
1	0	1	3
1	1	1	4

X = Don't Care

PIN CONFIGURATIONS**DIP/SOIC/TSSOP****DIP/SOIC/TSSOP**

ADG608/ADG609—Typical Performance Characteristics

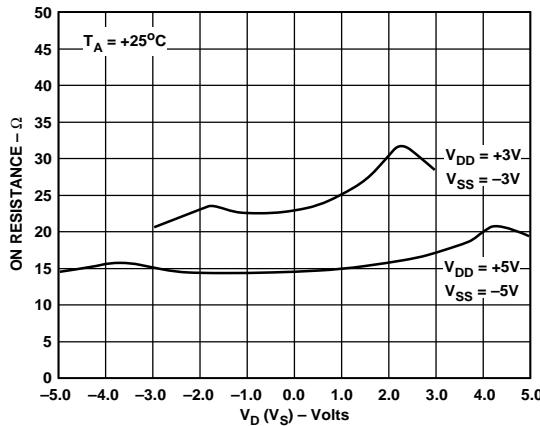


Figure 1. R_{ON} as a Function of $V_D (V_S)$: Dual Supply Voltage

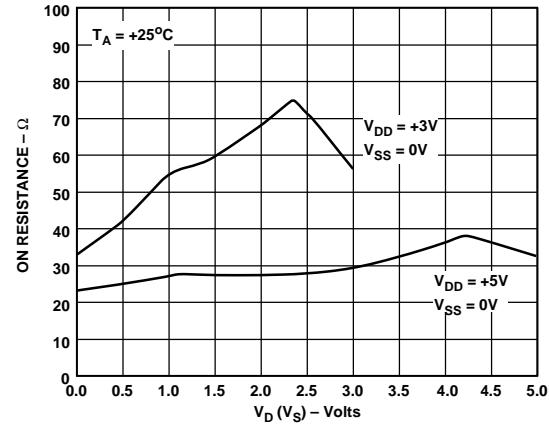


Figure 4. R_{ON} as a Function of $V_D (V_S)$: Single Supply Voltage

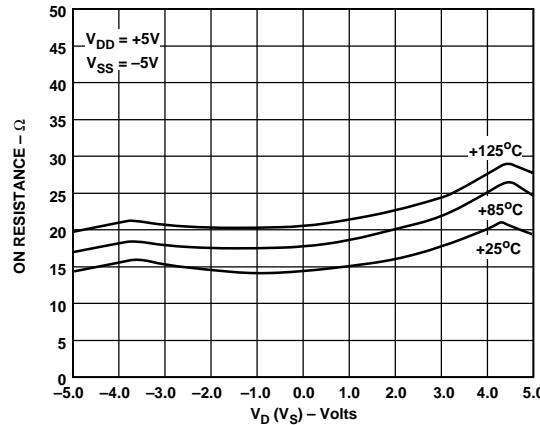


Figure 2. R_{ON} as a Function of $V_D (V_S)$ for Different Temperatures

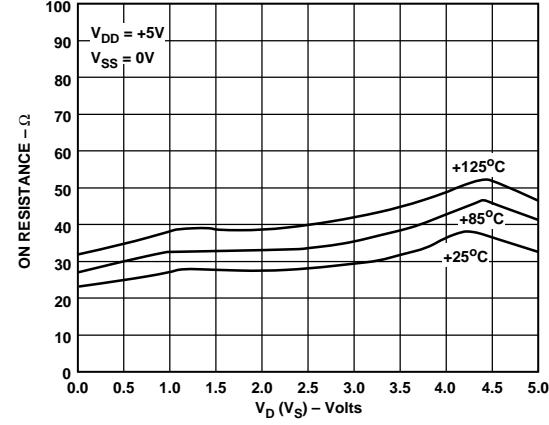


Figure 5. R_{ON} as a Function of $V_D (V_S)$ for Different Temperatures

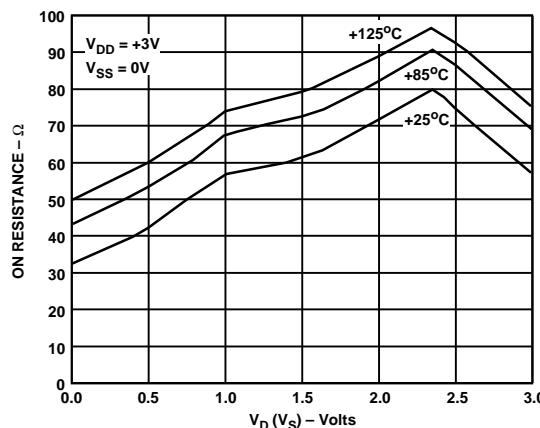


Figure 3. R_{ON} as a Function of $V_D (V_S)$ for Different Temperatures

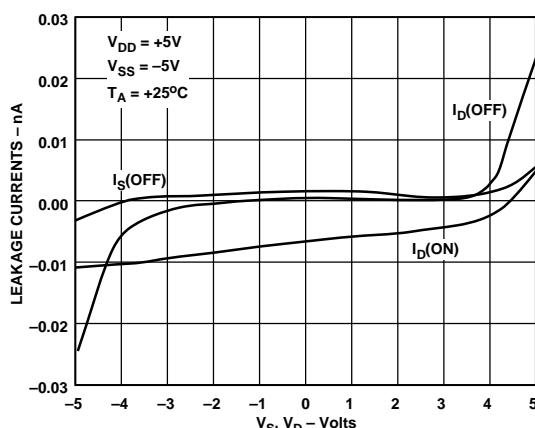


Figure 6. Leakage Currents as a Function of $V_D (V_S)$

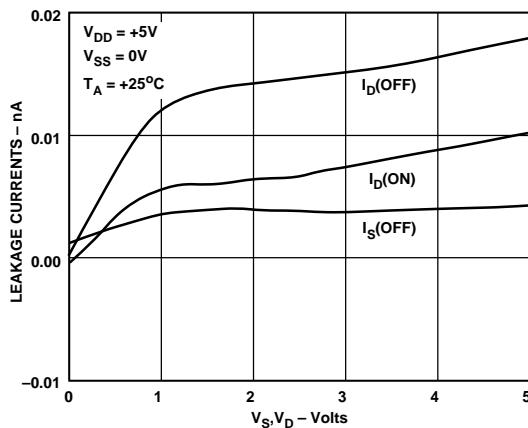


Figure 7. Leakage Currents as a Function of V_D (V_S)

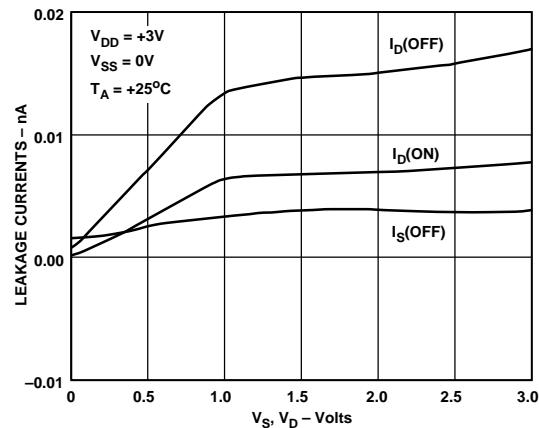


Figure 10. Leakage Currents as a Function of V_D (V_S)

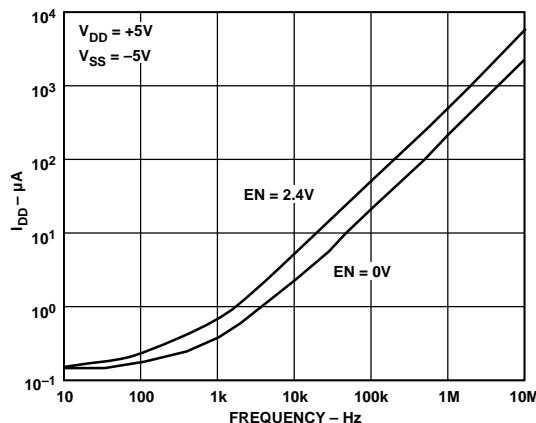


Figure 8. Positive Supply Current vs. Switching Frequency

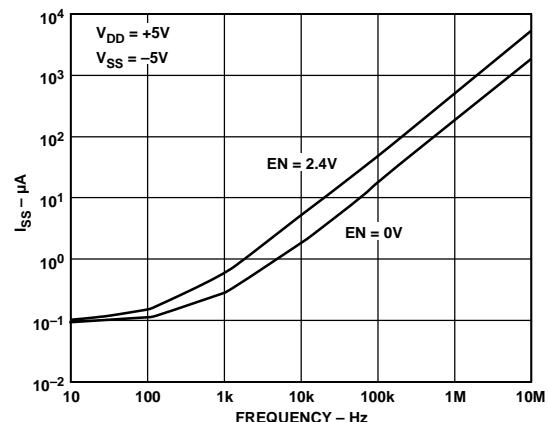


Figure 11. Negative Supply Current vs. Switching Frequency

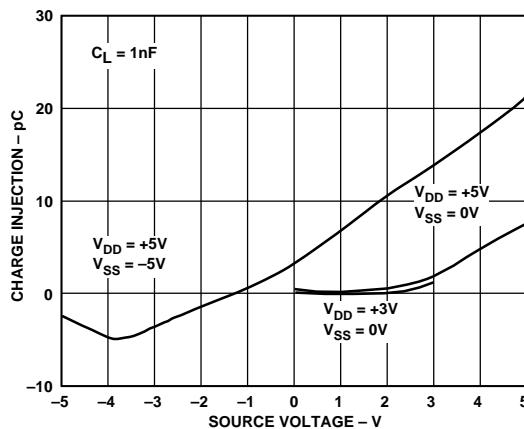


Figure 9. Charge Injection vs. Analog Voltage V_S

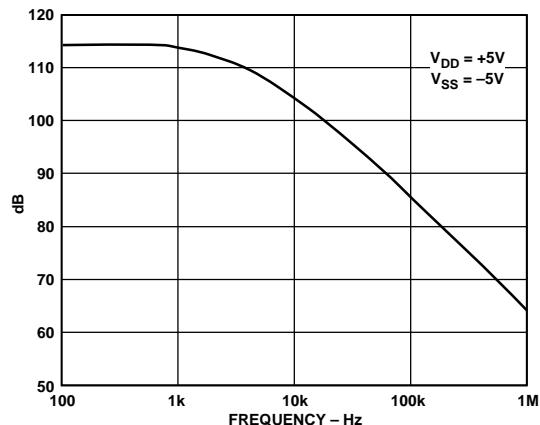
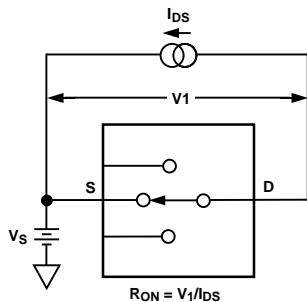


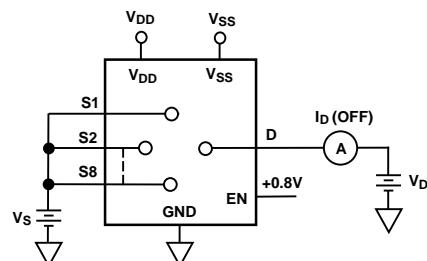
Figure 12. Crosstalk and Off Isolation vs. Frequency

ADG608/ADG609

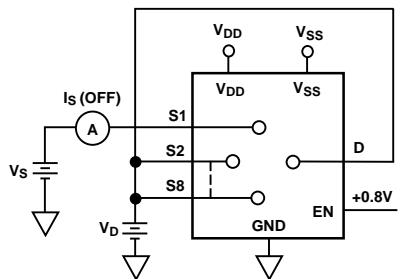
Test Circuits



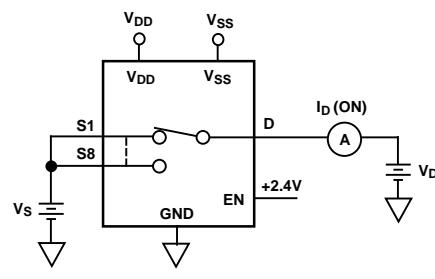
Test Circuit 1. On Resistance



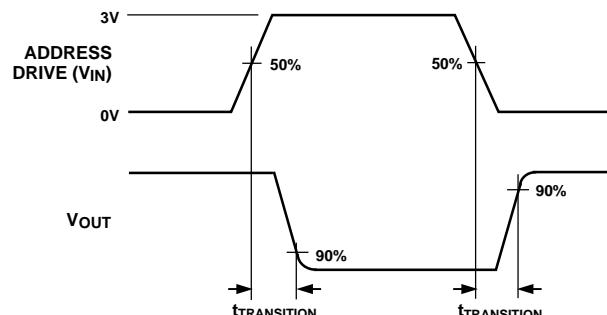
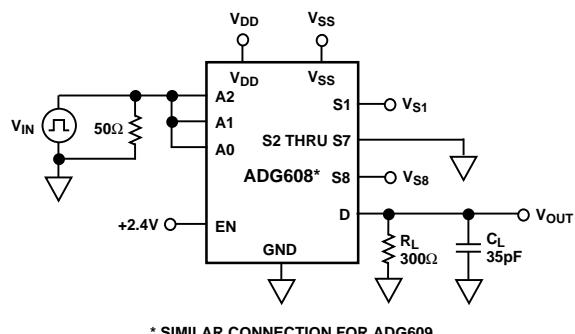
Test Circuit 3. $I_D(OFF)$



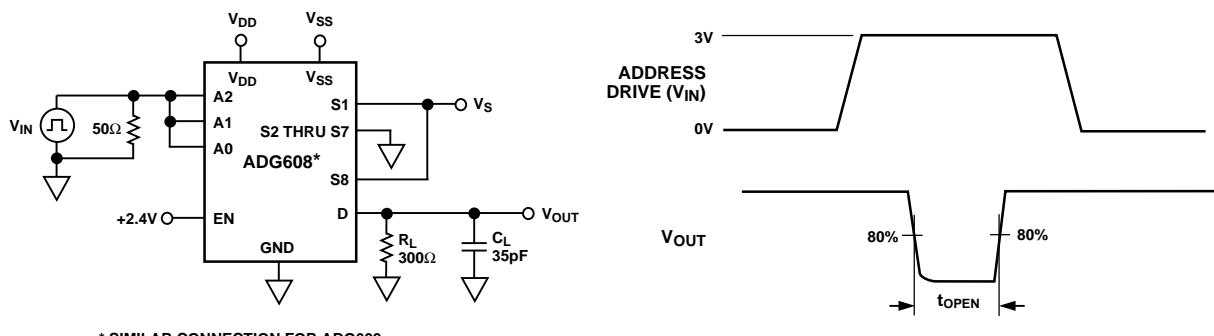
Test Circuit 2. $I_s(OFF)$



Test Circuit 4. $I_D(ON)$

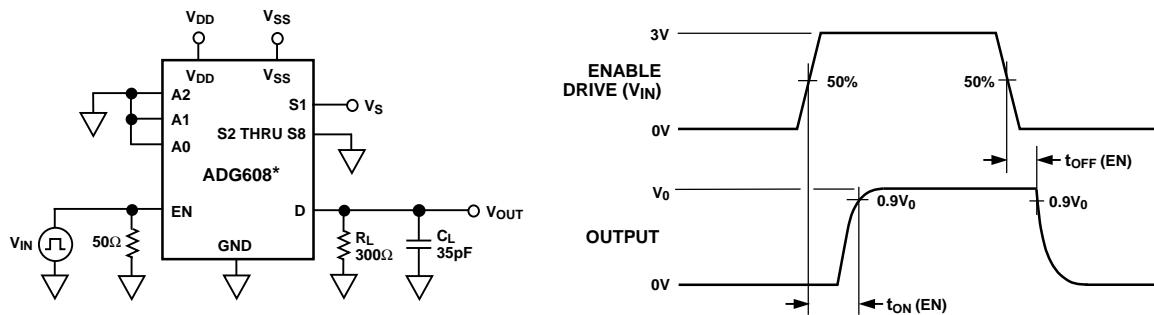


Test Circuit 5. Switching Time of Multiplexer, $t_{TRANSITION}$



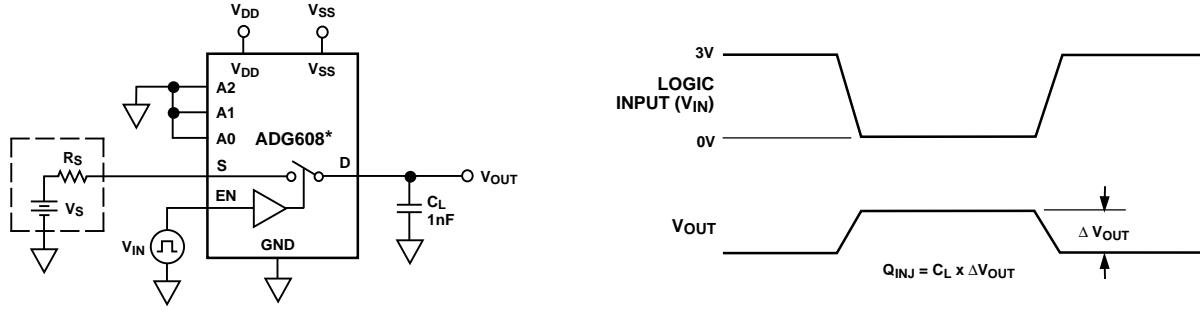
* SIMILAR CONNECTION FOR ADG609

Test Circuit 6. Break-Before-Make Delay, t_{OPEN}



* SIMILAR CONNECTION FOR ADG609

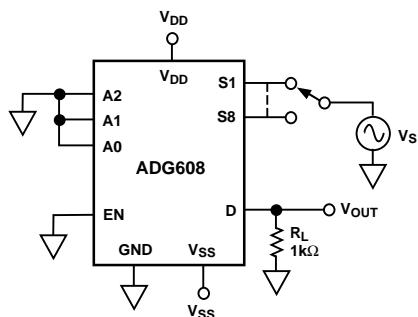
Test Circuit 7. Enable Delay, $t_{ON}(EN)$, $t_{OFF}(EN)$



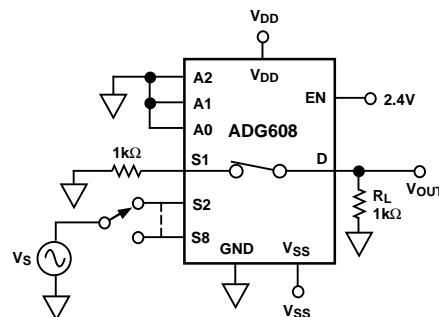
* SIMILAR CONNECTION FOR ADG609

Test Circuit 8. Charge Injection

ADG608/ADG609



Test Circuit 9. OFF Isolation



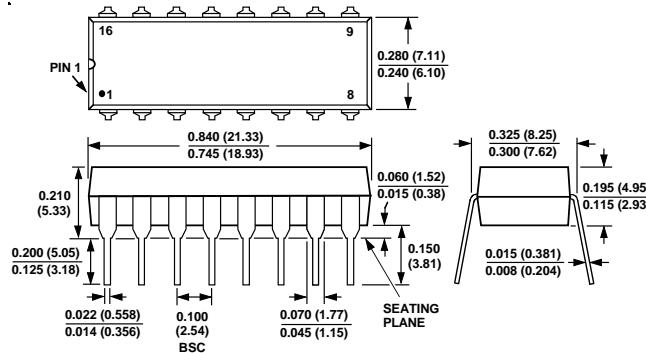
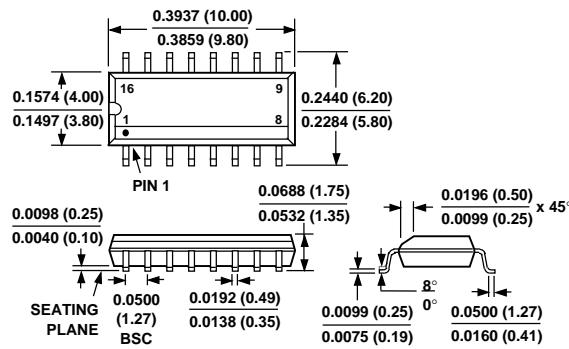
Test Circuit 10. Channel-to-Channel Crosstalk

TERMINOLOGY

V _{DD}	Most positive power supply potential.	t _{OFF} (EN)	Delay time between the 50% and 90% points of the digital input and switch “OFF” condition.
V _{SS}	Most negative power supply potential in dual supplies. In single supply applications, it may be connected to ground.	t _{TRANSITION}	Delay time between the 50% and 90% points of the digital inputs and the switch “ON” condition when switching from one address state to another.
GND	Ground (0 V) reference.	t _{OPEN}	“OFF” time measured between the 80% points of both switches when switching from one address state to another.
R _{ON}	Ohmic resistance between D and S.	V _{INL}	Maximum input voltage for logic “0.”
ΔR _{ON}	R _{ON} variation due to a change in the analog input voltage with a constant load current.	V _{INH}	Minimum input voltage for logic “1.”
R _{ON} Match	Difference between the R _{ON} of any two channels.	I _{INL} (I _{INH})	Input current of the digital input.
I _S (OFF)	Source leakage current when the switch is off.	Crosstalk	A measure of unwanted signal which is coupled through from one channel to another as a result of parasitic capacitance.
I _D (OFF)	Drain leakage current when the switch is off.	Off Isolation	A measure of unwanted signal coupling through an “OFF” channel.
I _D , I _S (ON)	Channel leakage current when the switch is on.	Charge Injection	A measure of the glitch impulse transferred from the digital input to the analog output during switching.
V _D , V _S	Analog voltage on terminals D, S.	I _{DD}	Positive supply current.
C _S (OFF)	Channel input capacitance for “OFF” condition.	I _{SS}	Negative supply current.
C _D (OFF)	Channel output capacitance for “OFF” condition.		
C _D , C _S (ON)	“ON” switch capacitance.		
C _{IN}	Digital input capacitance.		
t _{ON} (EN)	Delay time between the 50% and 90% points of the digital input and switch “ON” condition.		

OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

16-Pin Plastic (N-16)**16-Pin SOIC (R-16A)****16-Pin TSSOP (RU-16)**